


**FAST SOFT RECOVERY
RECTIFIER DIODE**

	V_F	< 1.41V @ 30A
	t_{rr}	= 95 ns
	V_{RRM}	1000 to 1200V

Description/Features

The 30EPF.. & 30CPF.. soft recovery **QUIETIR** rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

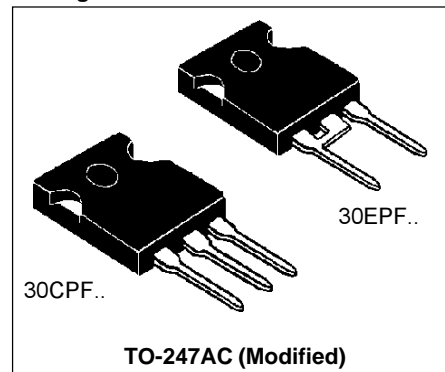
Typical applications are:

- Output rectification and freewheeling in inverters, choppers and converters
- and input rectifications where severe restrictions on conducted EMI should be met.
- 30CPF series is a drop in replacement for 25CPF Series (parallel connection only)

Major Ratings and Characteristics

Characteristics	30EPF.. 30CPF..	Units
$I_{F(AV)}$ Sinusoidal waveform	30	A
V_{RRM}	1000 to 1200	V
I_{FSM}	350	A
V_F @ 30A, $T_J = 25^\circ\text{C}$	1.41	V
t_{rr} @ 1A, 100A/ μs	95	ns
T_J	-40 to 150	$^\circ\text{C}$

Package Outline



30EPF.. 30CPF.. HV QUIETIR Series

Preliminary Data Sheet I2138 09/97

International
IR Rectifier

Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
30EPF10, 30CPF10	1000	1100	6
30EPF12, 30CPF12	1200	1300	

Absolute Maximum Ratings

Parameters	30.PF..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	30	A	@ $T_C=95^\circ\text{C}$, 180° conduction half sine wave
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	300	A	10ms Sine pulse, rated V_{RRM} applied
	350		10ms Sine pulse, no voltage reapplied
I^2t Max. I^2t for fusing	450	2_s	10ms Sine pulse, rated V_{RRM} applied
	636		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	6360	$A^2\sqrt{s}$	t=0.1 to 10ms, no voltage reapplied

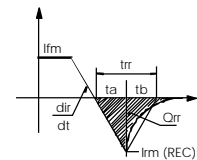
Electrical Specifications

Parameters	30.PF..	Units	Conditions
V_{FM} Max. Forward Voltage Drop	1.41	V	@ 30A, $T_J = 25^\circ\text{C}$
r_t Forward slope resistance	10.09	$m\Omega$	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.992	V	
I_{RM} Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$
	6		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

Typical Recovery Characteristics

Parameters	30.PF..	Units	Conditions
t_{rr} Reverse Recovery Time	450	ns	$I_F @ 30\text{Apk}$ @ 25A/ μs @ 25°C
I_{rr} Reverse Recovery Current	6.1	A	
Q_{rr} Reverse Recovery Charge	2.16	μC	
S Snap Factor t_b/t_a	0.6	typical	



Thermal-Mechanical Specifications

Parameters	30.PF..	Units	Conditions
T_J Max. Junction Temperature Range	-40 to 150	°C	
T_{stg} Max. Storage Temperature Range	-40 to 150	°C	
R_{thJC} Max. Thermal Resistance Junction to Case	0.8	°C/W	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	40	°C/W	
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.2	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	6(0.21)	g(oz.)	
T Mounting Torque	Min.	6(5)	Kg-cm (lbf-in)
	Max.	12(10)	
Case Style	TO-247AC		JEDEC (Modified)

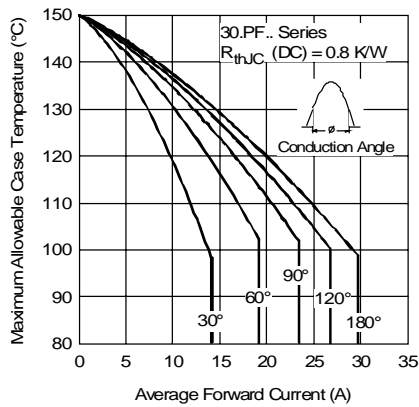


Fig. 1 - Current Rating Characteristics

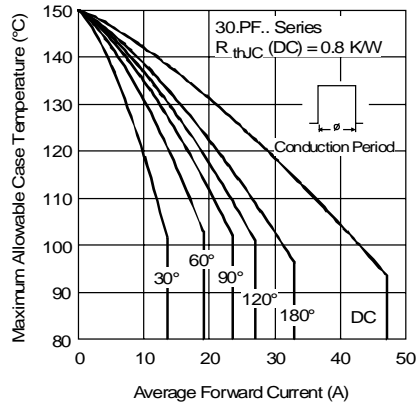


Fig. 2 - Current Rating Characteristics

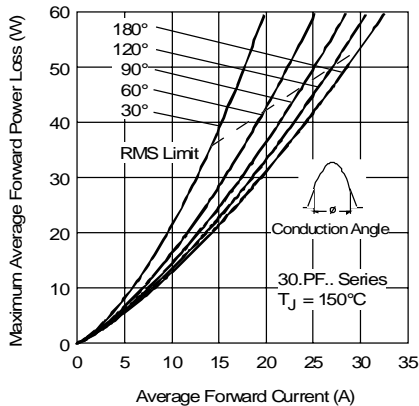


Fig. 3 - Forward Power Loss Characteristics

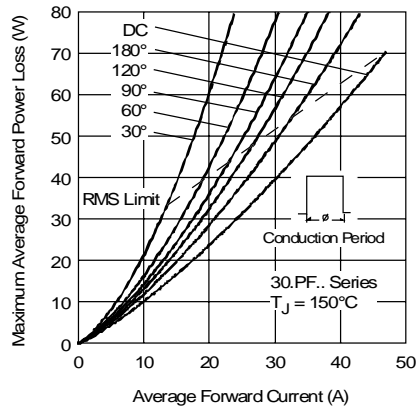


Fig. 4 - Forward Power Loss Characteristics

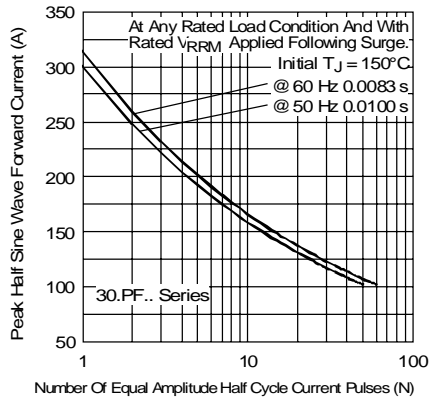


Fig. 5 - Maximum Non-Repetitive Surge Current

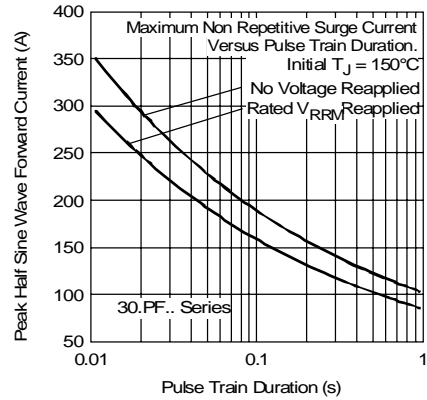


Fig. 6 - Maximum Non-Repetitive Surge Current

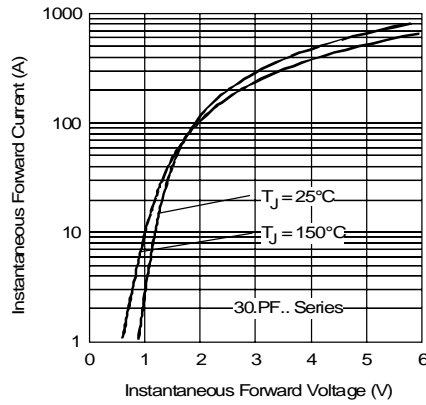


Fig. 7 - Forward Voltage Drop Characteristics

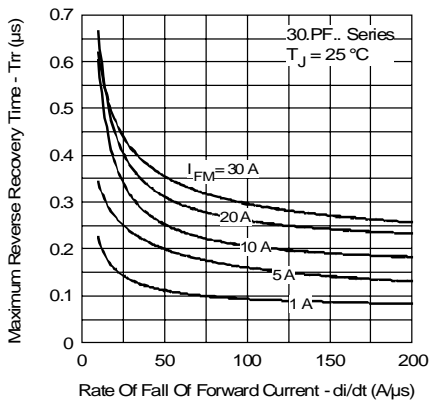


Fig. 8 - Recovery Time Characteristics, $T_J = 25^\circ\text{C}$

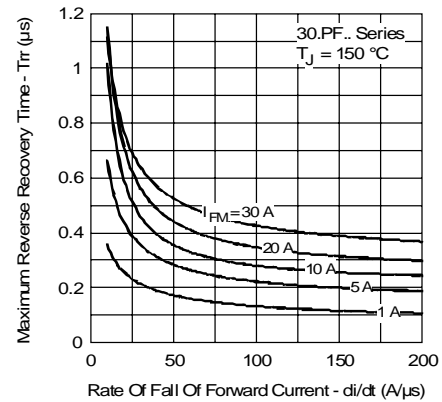


Fig. 9 - Recovery Time Characteristics, $T_J = 150^\circ\text{C}$

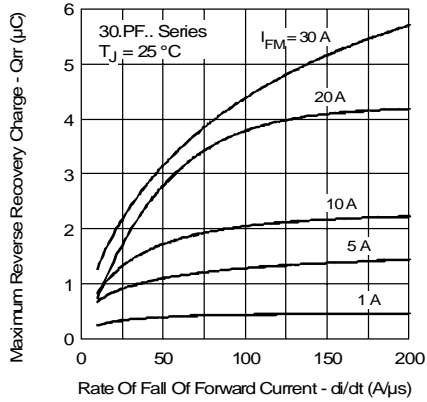


Fig. 10 - Recovery Charge Characteristics, $T_J = 25^\circ\text{C}$

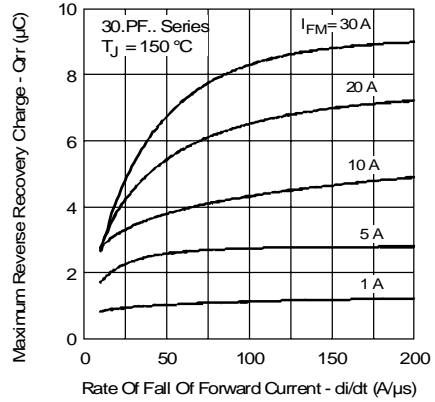


Fig. 11 - Recovery Charge Characteristics, $T_J = 150^\circ\text{C}$

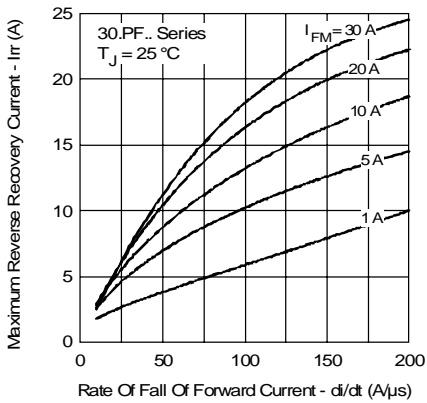


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ\text{C}$

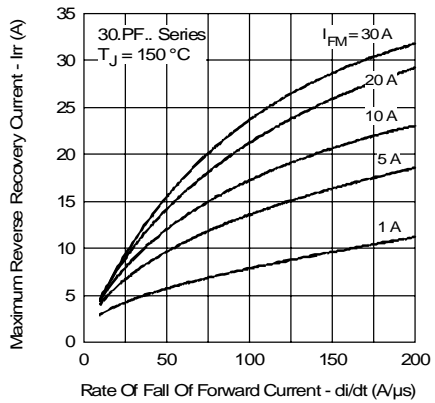


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ\text{C}$

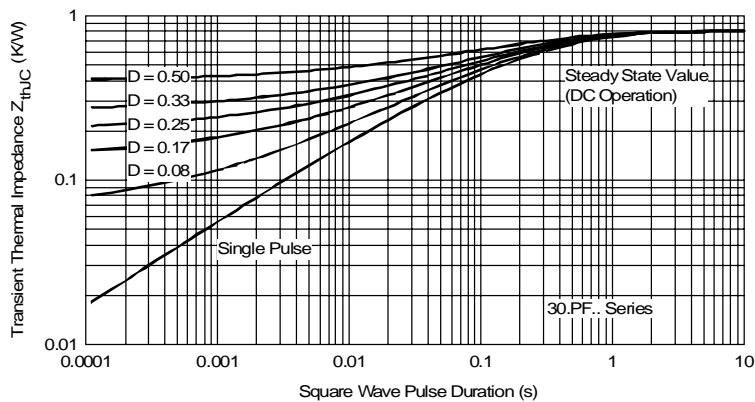


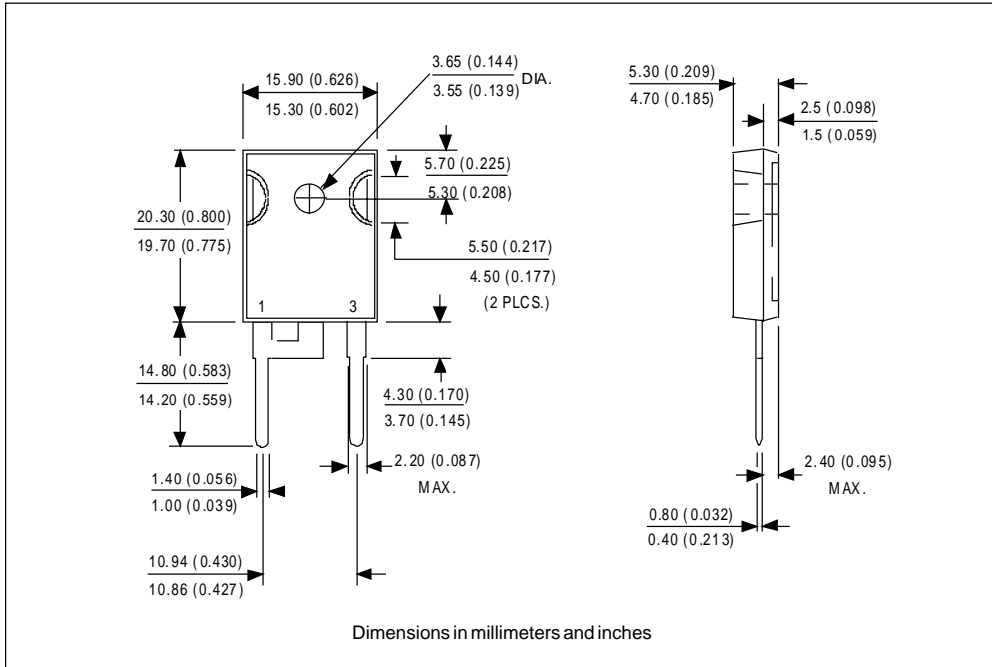
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

30EPF.. 30CPF.. HV QUIETIR Series

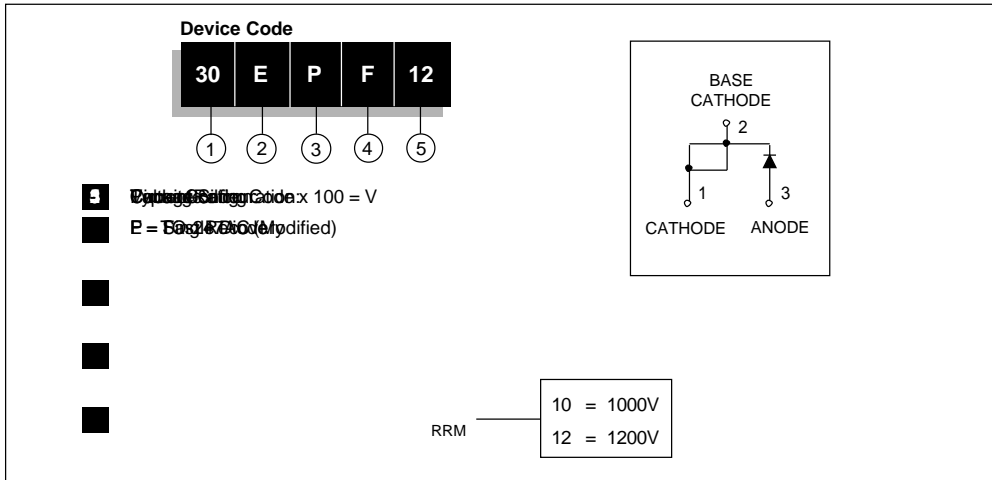
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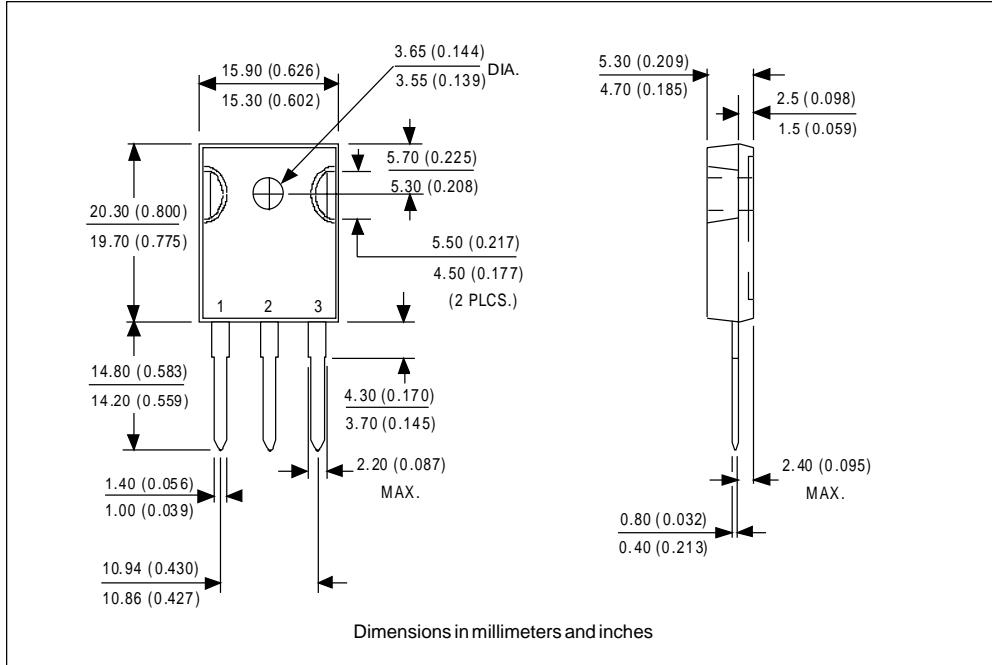
Outline Table



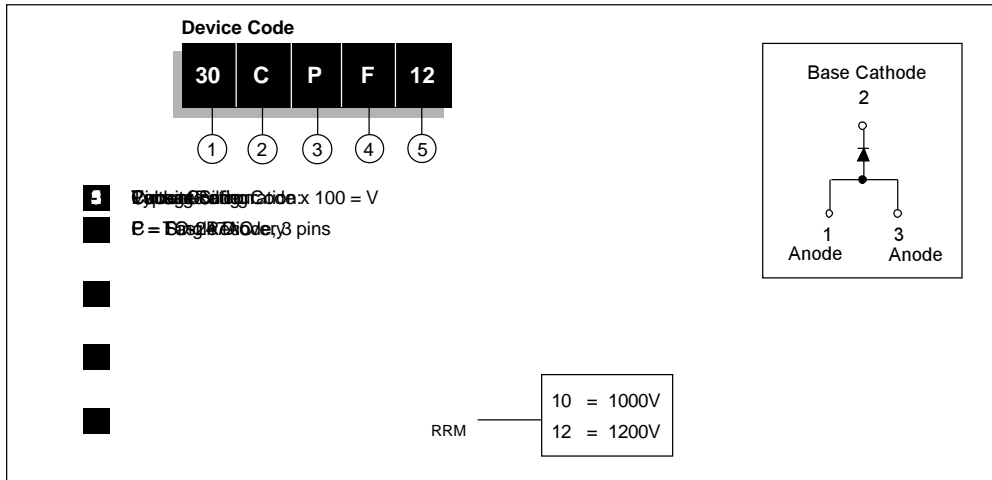
Ordering Information Table



Outline Table



Ordering Information Table





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